Ink. t. Patent- och reg.verket

2004 -01- 26

Huyudiaxan Kassan

## Abstract

In recent years there has been a growing market for more universal analysis instruments. Analysis tools such as AFM<sup>1</sup>, TEM<sup>2</sup> and nanoindentation work in similar environments. It is therefore possible, within limits, to use the same equipment to do all of these analyses. Conducting nanoindentation experiments in a TEM has also the advantage of increased accuracy compared to the tests done today.

This project is focused on design and fabrication of a capacitive force sensor for AFM and/or nanoindentation measurements in a TEM. Nanofactory Instruments, the initiator of this project, has developed a specimen holder for TEM that can be used for nanoindentation experiments. The measurement system used today has its limitations of being to large to be mounted in a TEM and thus an improved model was desired.

The idea to combine an AFM and nanoindenter sensor in the same design is however at 1 is stage inhibited by a relatively large diamond tip that was specified for the nanoindentation experiments. The work was therefore concentrated on the design and fabrication of a nanoindenter senor. The design is done with an integrated fixture for a diamond tip with specified dimensions. The sensor design has been manufactured using double-sided lithography, DRIE<sup>3</sup> etch and anodic bonding. The resulting wafer was sawed into comparents and the components were evaluated.

Evaluation of the sensor shows that it was possible to manufacture a micromachined nanoindenter sensor with an integrated fixture for a standard diamond tip. CV<sup>4</sup>-measurements conducted with HP 4284A indicates a force dependent capacitance change when a force within the specification range is applied. Future work will involve a more detailed characterization using a read-out chip from SmartTec.

<sup>1</sup> Atomic Force Microscopy

<sup>&</sup>lt;sup>2</sup> Transmission Blectron Microscope

<sup>&</sup>lt;sup>3</sup> Dry Reactive Ion Etch

<sup>&</sup>lt;sup>4</sup> Capacitance-Voltage measurements